Modeling CuS-CdSe Solar Cell S-Shaped I-V Characteristics

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The process of designing practical photovoltaic applications calls for the availability of dc lumped-parameter equivalent circuit models. The electrical characteristics of thin film CuS_{1.8}–CdSe solar cell are more complex than conventional photovoltaic devices; varying from an ideal 'J' shape to a non-ideal 'S' shape with a 'kink' in the current-voltage (I-V) plot when under illumination – see Fig.1. Our work is focused on the determination of the proper equivalent model of CuS–CdSe structure by using the I-V characteristics, which have been measured over a temperature range 290-340 K.

The model, proposed in [1], was chosen as an initial approximation. The experimental I-V characteristics were fitted by the exact closed form analytical solution, which uses the Lambert W function [2]. To avoid the risk of numerical overflow in the calculation, the solution was rewritten by using the g(x) function [3]. The analysis has been shown that i) the effect of series resistance must be omitted for illuminated I-V plot; ii) dark I-V characteristics are fitted by the conventional single diode model quote enough – see Fig.2. The temperature dependencies of the shunt resistances and the both saturation currents and ideality factors of the diodes were determined.

^[1] F. A. de Castro *et al.*, IEEE J. Sel. Top. Quantum Electron **16**, 1690 (2010)

^[2] B. Romero, G. del Pozo, B. Arredondo, Solar Energy 86 3026-3029 (2012).

^[3] K, Roberts, S. R. Valluri, arXiv preprint arXiv:1601.02679 (2015)

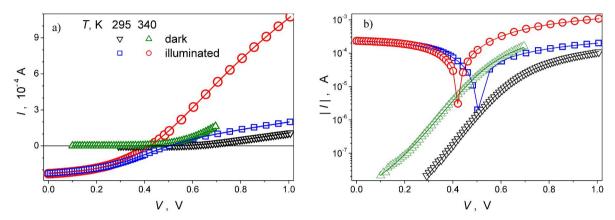


Fig.1. The dark (triangles) and illuminated (circles and squares) I-V curves for CuS-CdSe solar cell at different temperatures. The experimental (marks) and fitted (solid lines) results are presented.

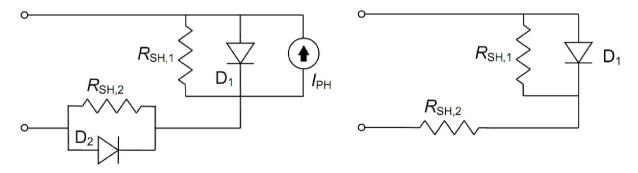


Fig.2. The proposed DC lumped-parameter equivalent circuit model of CuS-CdSe solar cell under illumination (left) and dark condition (right).